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Vishay Semiconductors

Power Rectifier Diodes (T-Modules), 2200 V, 20 A



D-55 (T-module)

PRODUCT SUMMARY					
I _{F(AV)}	20 A				
Туре	Modules - Diode, High Voltage				
V _{RRM}	2200 V				
Package	D-55 (T-module)				
Circuit	Single diode				

FEATURES

- · Electrically isolated base plate
- 2200 V_{RRM}
- Industrial standard packaging
- UL approved file E78996



- · Simplified mechanical designs, rapid assembly
- · Large creepage distances
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

These series of T-modules use standard recovery power rectifier diodes. The semiconductors are electrically isolated from the metal base, allowing common heatsink and compact assembly to be built.

Applications include power supplies, battery charges, welders, motor controls, and solar panel application.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
		20	А			
I _{F(AV)}	T _C	85	°C			
I _{F(RMS)}		31				
I _{FSM}	50 Hz	450	Α			
	60 Hz	470				
2 	50 Hz	1015	A ² s			
1-1	60 Hz	920	A-S			
I ² √t		10 125	A²√s			
V _{RRM}		2200	V			
T _J		-40 to +150	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA				
T20HF220	22	2200	2250	18				



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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			20 85	A °C	
Maximum RMS forward current	I _{F(RMS)}				31	Α	
	, ,	t = 10 ms	No voltage		450		
Maximum peak, one-cycle forward,	1	t = 8.3 ms	reapplied		470	A	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}	0::	380	A	
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial	400		
		t = 10 ms	No voltage	$T_J = T_J$ maximum	1015	A ² s	
Maximum I ² t for fusing	I ² t	t = 8.3 ms	reapplied		920		
Waxiinum I-t for fusing		t = 10 ms	100 % V _{RRM}		715		
		t = 8.3 ms	reapplied		650		
Maximum l ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			10 125	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), I_{J} maximum			0.77	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J$ maximum			0.89		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), I_{J} maximum			8.5	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J \text{ maximum}$			6.7		
Maximum forward voltage drop	V _{FM}	$I_{FM} = 60 \text{ A}$, $T_J = 25 \text{ °C}$, $t_p = 400 \text{ µs square pulse}$ Average power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$			1.50	V	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	18	mA
RMS isolation voltage	V _{ISOL}	50 Hz, circuit to base, all terminals shorted $T_J = 25 ^{\circ}\text{C}$, $t = 1 \text{s}$	3500	V

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TES	T CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	and storage	T _J , T _{Stg}			-40 to +150	°C	
Maximum thermal resistance, per junction	junction to case	R _{thJC}	DC operation		2.53	K/W	
Maximum thermal resistance,	case to heatsink	R _{thCS}	Mounting surface smooth, flat and greased		0.2		
Mounting torque + 10.0/	to heatsink		Non-lubricated	M3.5 mounting screws (1)	1.3 ± 10 %	Nm	
Mounting torque, ± 10 % —	terminals		threads M5 screw terminals		3 ± 10 %	INIII	
Approximate weight			See dimensions	- link at the end of datasheet	54	g	
Case style					D-55 (T-m	odule)	

Note

⁽¹⁾ A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound

△R CONDUCTION PER JUNCTION											
DEVICES	SINUSOIDAL CONDUCTION AT TJ MAXIMUM				RECTANGULAR CONDUCTION AT T _J MAXIMUM				UNITS		
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
T20HF	0.29	0.34	0.43	0.64	1.10	0.20	0.35	0.47	0.67	1.11	K/W

Note

• Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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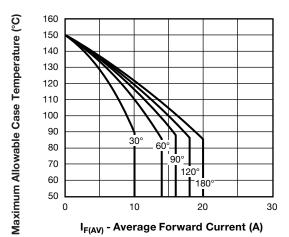


Fig. 1 - Current Ratings Characteristics

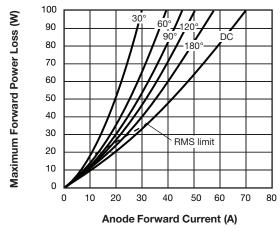


Fig. 4 - Forward Power Loss Characteristics

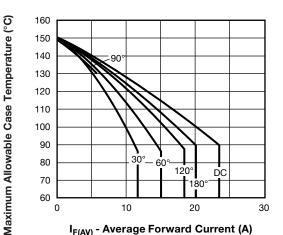


Fig. 2 - Current Ratings Characteristics

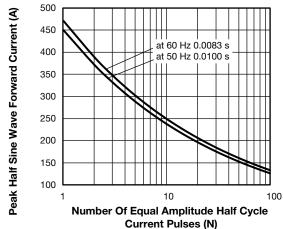


Fig. 5 - Maximum Non-Repetitive Surge Current

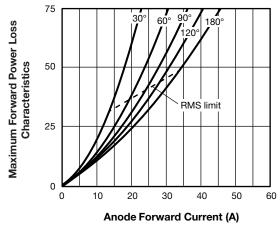


Fig. 3 - Forward Power Loss Characteristics

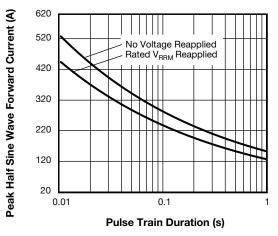


Fig. 6 - Maximum Non-Repetitive Surge Current

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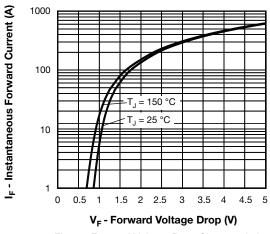


Fig. 7 - Forward Voltage Drop Characteristics

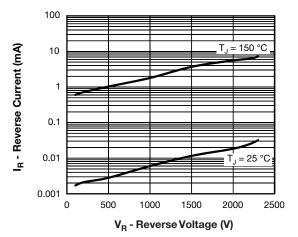


Fig. 8 - Typical Values of Reverse Current vs. Reverse Voltage

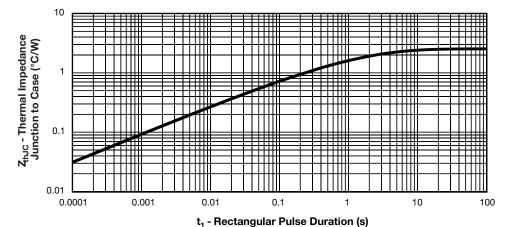
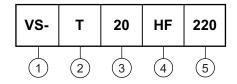


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Module type

3 - Current rating

4 - Circuit configuration (see Circuit Configuration table)

Voltage code x 10 = V_{RRM}

CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Single diode	HF	2 0 0 1

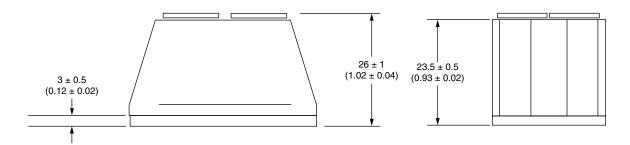
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95313

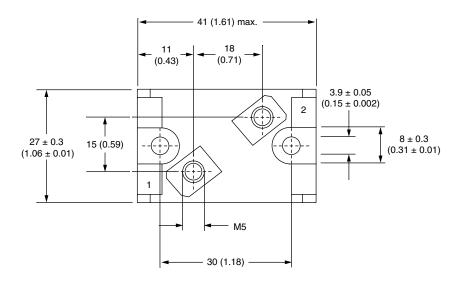


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D-55 T-Module Diode Standard and Fast Recovery

DIMENSIONS in millimeters (inches)





Note

1 = Anode2 = Cathode



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